

**DL-3149-056****Index Guided AlGaInP Laser Diode****Overview**

DL-3149-056 is 670 nm (Typ.) index guided AlGaInP laser diode with low threshold current. The low threshold current and short wavelength are achieved by the use of a strained multiple quantum well active layer.

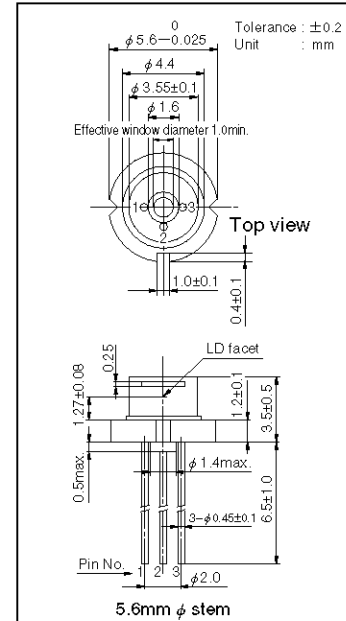
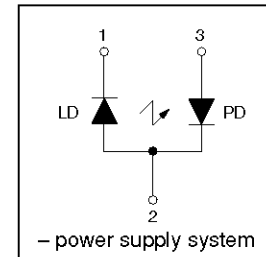
DL-3149-056 is suitable for laser pointers .

Features

- Short wavelength : 670 nm (Typ.)
- Output power : 3mW CW
- Low threshold current : $I_{th} = 35\text{mA}$ (Typ.)
- Small package : 5.6 mm ϕ

Absolute Maximum Ratings at $T_c=25^\circ\text{C}$

Parameter	Symbol	Ratings	Unit
Light Output	P_o	5	mW
Reverse Voltage	Laser PIN V_R	2	V
		30	
Operating Temperature	T_{opr}	-10 to +50	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to +85	$^\circ\text{C}$

Package Dimensions**Electrical Connection****Electrical and Optical Characteristics at $T_c=25^\circ\text{C}$**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Threshold Current	I_{th}	CW	-	35	60	mA
Operating Current	I_{op}	$P_o=3\text{mW}$	-	45	70	mA
Operating Voltage	V_{op}	$P_o=3\text{mW}$	-	2.3	2.6	V
Lasing Wavelength	λ_p	$P_o=3\text{mW}$	660	670	685	nm
Beam Divergence ※)	Perpendicular	θ_{\perp}	25	33	40	deg.
	Parallel	θ_{\parallel}	6	8	10	deg.
Off Axis Angle	Perpendicular	$\Delta\theta_{\perp}$	-	-	±3	deg.
	Parallel	$\Delta\theta_{\parallel}$	-	-	±3	deg.
Differential Efficiency	dP_o/dI_{op}	-	-	0.3	-	mW/mA
Monitoring Output Current	I_m	$P_o=3\text{mW}$	0.2	0.7	1.4	mA
Astigmatism	A_s	$P_o=3\text{mW}$	-	10	-	μm

※) Full angle at half maximum note : The above product specifications are subject to change without notice.

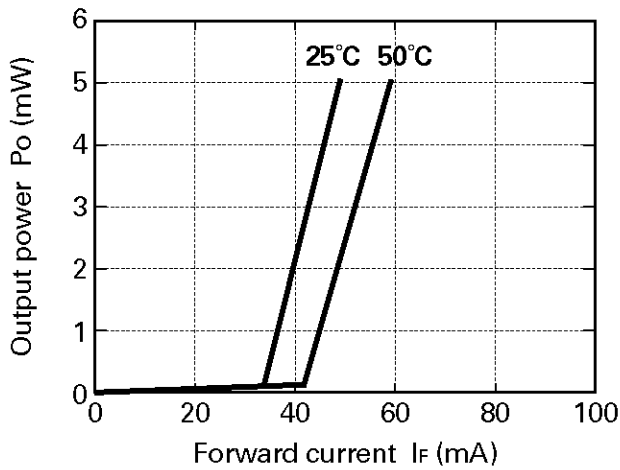
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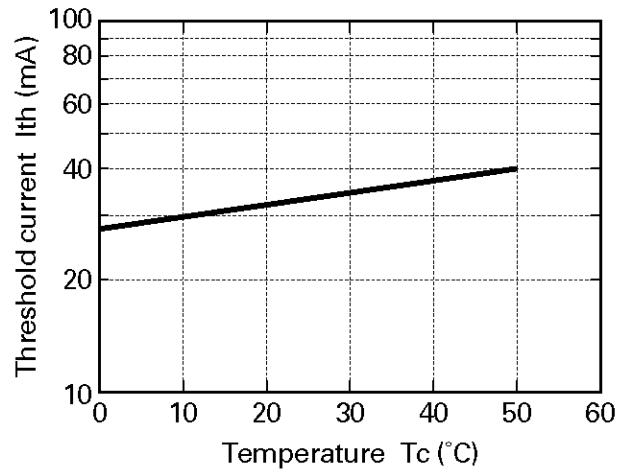
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Characteristics

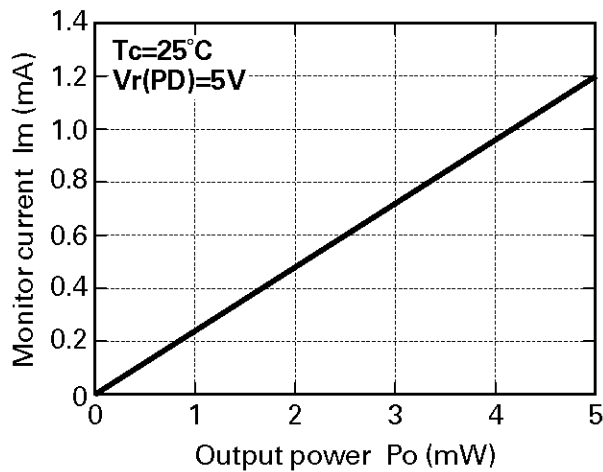
Output power vs. Forward current



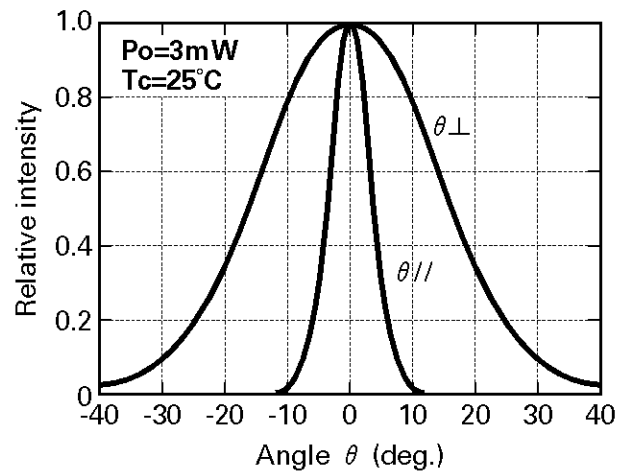
Threshold current vs. Temperature



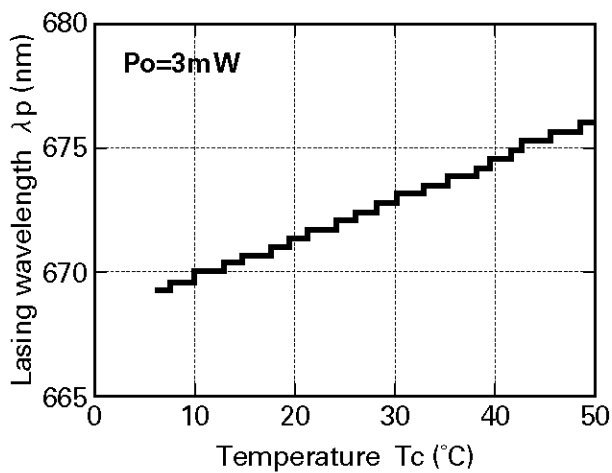
Monitor current vs. Output power



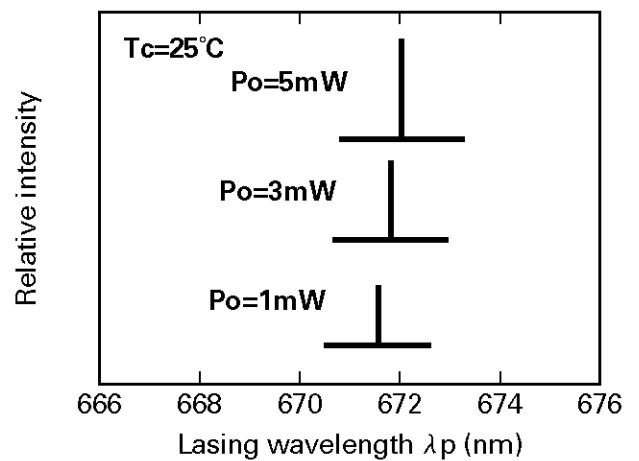
Beam divergence



Lasing wavelength vs. Temperature



Output power vs. Lasing wavelength



CAUTION

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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

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